

# ZXTP23015CFH

## 15V, SOT23, PNP medium power transistor

### Summary

$V_{(BR)CES} > -15V, V_{(BR)CEO} > -15V$

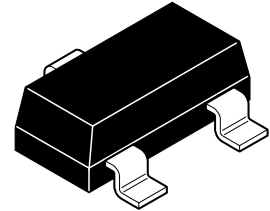
$V_{(BR)ECO} > -6V$

$I_{C(CONT)} = -6A$

$R_{CE(SAT)} = 20m\Omega$  typical

$V_{CE(SAT)} < -36mV @ -1A$

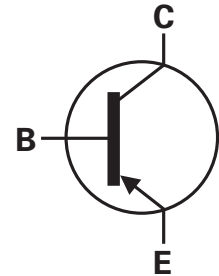
$P_D = 1.25W$



Complementary part number ZXTN23015CFH

### Description

Advanced process capability and package design have been used to maximize the power handling and performance of this small outline transistor. The compact size and ratings of this device make it ideally suited to applications where space is at a premium.

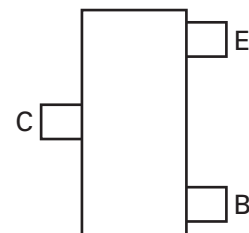


### Feature

- Higher power dissipation SOT23 package
- High peak current
- Low saturation voltage
- 15V forward blocking voltage
- 6V reverse blocking voltage

### Applications

- High side disconnect switches
- DC - DC converters
- MOSFET and IGBT gate driving
- Motor drive
- Relay, lamp, and solenoid drive



Pinout - top view

### Ordering information

Device	Reel size (inches)	Tape width	Quantity per reel
ZXTP23015CFHTA	7	8mm	3000

### Device marking

317

# ZXTP23015CFH

## Absolute maximum ratings

Parameter	Symbol	Limit	Unit
Collector-base voltage	$V_{CBO}$	-15	V
Collector-emitter voltage	$V_{(BR)CES}$	-15	V
Collector-emitter voltage	$V_{CEO}$	-15	V
Emitter-base voltage	$V_{EBO}$	-7.0	V
Emitter-collector voltage	$V_{ECO}$	-6.0	V
Peak pulse current	$I_{CM}$	-10	A
Continuous collector current <sup>(c)</sup>	$I_C$	-5	A
Continuous collector current <sup>(d)</sup>	$I_C$	-6	A
Base current	$I_B$	-1.2	A
Power dissipation @ $T_A=25^{\circ}C$ <sup>(a)</sup> Linear derating factor <sup>(a)</sup>	$P_D$	0.73 5.84	W mW/°C
Power dissipation @ $T_A=25^{\circ}C$ <sup>(b)</sup> Linear derating factor <sup>(b)</sup>	$P_D$	1.05 8.4	W mW/°C
Power dissipation @ $T_A=25^{\circ}C$ <sup>(c)</sup> Linear derating factor <sup>(c)</sup>	$P_D$	1.25 9.6	W mW/°C
Power dissipation @ $T_A=25^{\circ}C$ <sup>(d)</sup> Linear derating factor <sup>(d)</sup>	$P_D$	1.81 14.5	W mW/°C
Operating and storage temperature	$T_j; T_{stg}$	-55 to +150	°C

## Thermal resistance

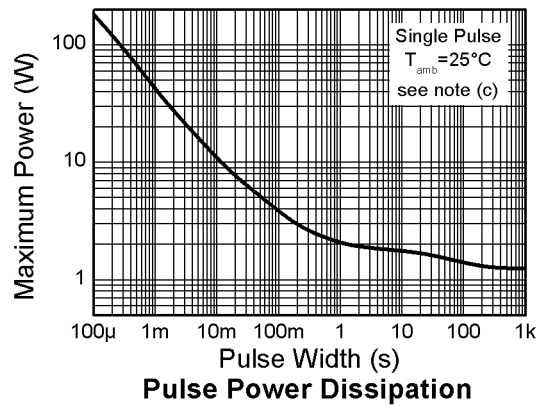
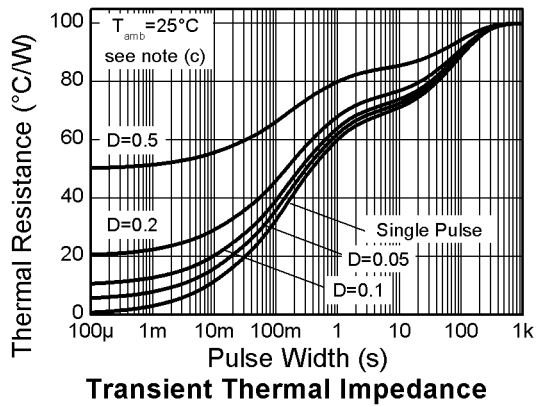
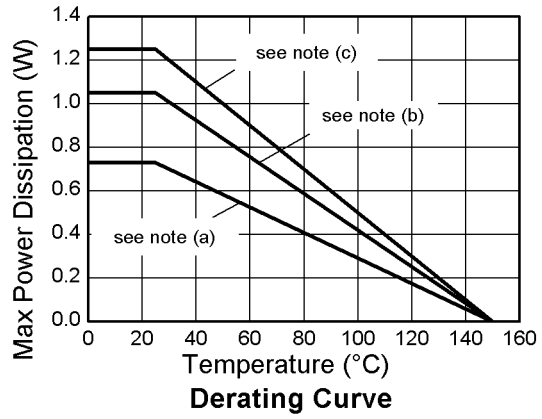
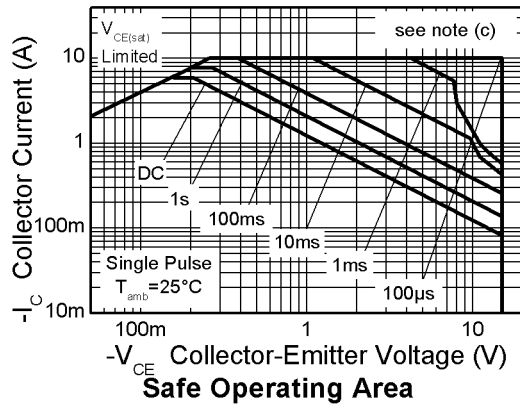
Parameter	Symbol	Value	Unit
Junction to ambient <sup>(a)</sup>	$R\theta_{JA}$	171	°C/W
Junction to ambient <sup>(b)</sup>	$R\theta_{JA}$	119	°C/W
Junction to ambient <sup>(c)</sup>	$R\theta_{JA}$	100	°C/W
Junction to ambient <sup>(d)</sup>	$R\theta_{JA}$	69	°C/W

### NOTES:

- (a) For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
- (b) Mounted on 25mm x 25mm x 1.6mm FR4 PCB with a high coverage of single sided 2 oz copper in still air conditions.
- (c) Mounted on 50mm x 50mm x 1.6mm FR4 PCB with a high coverage of single sided 2 oz copper in still air conditions.
- (d) As (c) above measured at  $t < 5$ secs.

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## Characteristics



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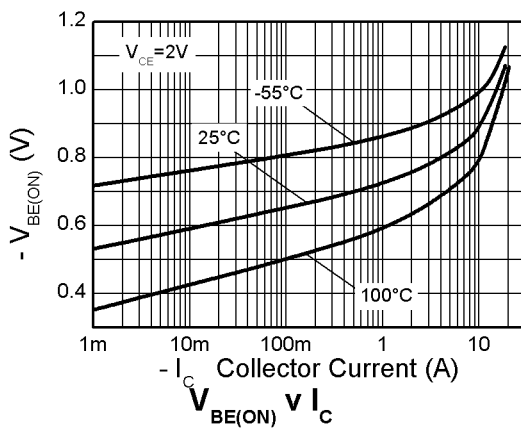
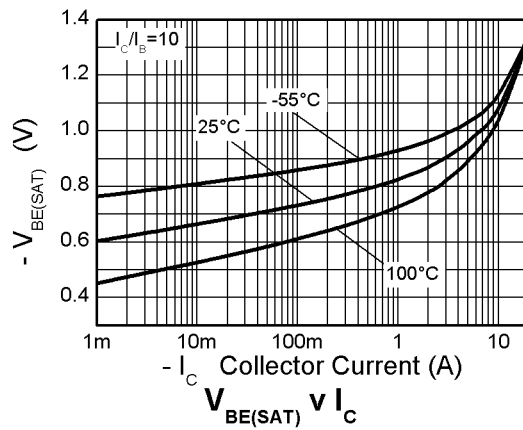
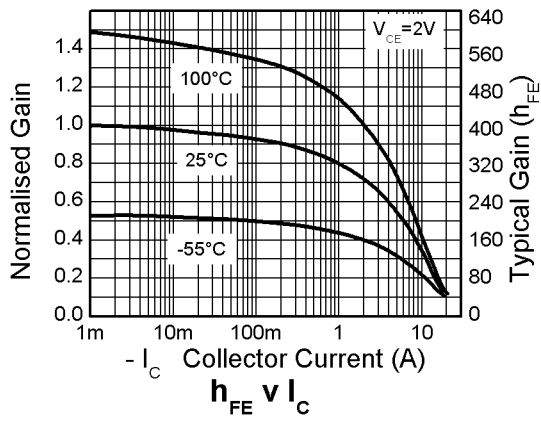
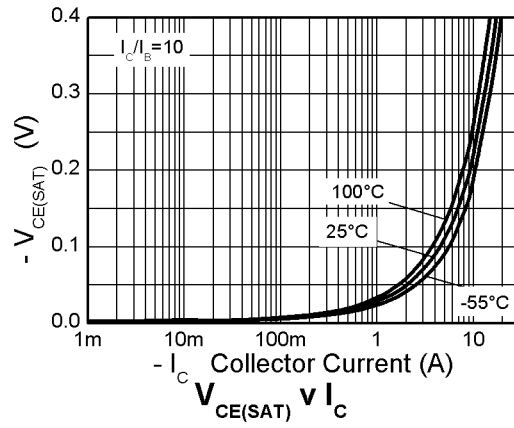
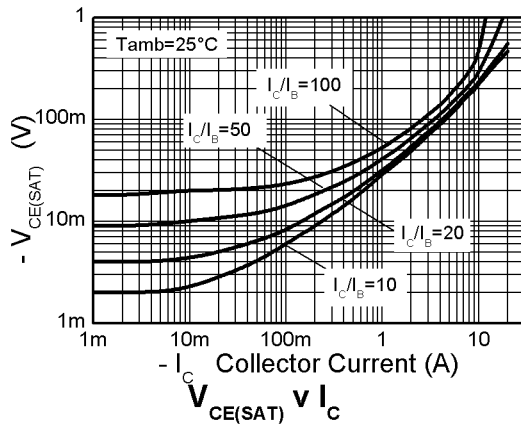
## ELECTRICAL CHARACTERISTICS (at $T_{AMB} = 25^{\circ}\text{C}$ unless otherwise stated)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	$V_{(BR)CBO}$	-15	-40		V	$I_C = -100\mu\text{A}$
Collector-emitter breakdown voltage	$V_{(BR)CES}$	-15	-40		V	$I_C = -100\mu\text{A}$
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	-15	-25		V	$I_C = -10\text{mA}^{(*)}$
Emitter-base breakdown voltage	$V_{(BR)EBO}$	-7.0	-8.2		V	$I_E = -100\mu\text{A}$
Emitter-collector breakdown voltage	$V_{(BR)ECO}$	-6.0	-8.5		V	$I_E = -100\mu\text{A}$
Collector-emitter cut-off current	$I_{CES}$			-20	nA	$V_{CE} = -12\text{V}$
Collector-base cut-off current	$I_{CBO}$			-20	nA	$V_{CB} = -12\text{V}$
Emitter-base cut-off current	$I_{EBO}$			-10	nA	$V_{EB} = -6\text{V}$
Static forward current transfer ratio	$H_{FE}$	200 200 140	380 350 220	560		$I_C = -10\text{mA}, V_{CE} = -2\text{V}^{(*)}$ $I_C = -500\text{mA}, V_{CE} = -2\text{V}$ $I_C = -6\text{A}, V_{CE} = -2\text{V}$
Collector-emitter saturation voltage	$V_{CE(sat)}$		-6 -27 -90 -140	-10 -36 -120 -190	mV mV mV mV	$I_C = -100\text{mA}, I_B = -10\text{mA}^{(*)}$ $I_C = -1\text{A}, I_B = -100\text{mA}^{(*)}$ $I_C = -3\text{A}, I_B = -60\text{mA}^{(*)}$ $I_C = -6\text{A}, I_B = -240\text{mA}^{(*)}$
Base-emitter saturation voltage	$V_{BE(sat)}$		-0.83 -0.93	-0.93 -1.03	V V	$I_C = -3\text{A}, I_B = -60\text{mA}^{(*)}$ $I_C = -6\text{A}, I_B = -240\text{mA}^{(*)}$
Base-emitter turn-on voltage	$V_{BE(on)}$		-0.83	-0.93	V	$I_C = -6\text{A}, V_{CE} = -2\text{V}^{(*)}$
Transition frequency	$f_T$		270		MHz	$I_C = -500\text{mA}, V_{CE} = -2\text{V}, f = 50\text{MHz}$
Output capacitance	$C_{obo}$		78.4		pF	$V_{CB} = -10\text{V}, f = 1\text{MHz}$
Delay time	$t_{(d)}$		16		ns	$V_{CC} = -5\text{V}, I_C = -3\text{A}, I_{B1} = I_{B2} = -150\text{mA}$
Rise time	$t_{(r)}$		13		ns	
Storage time	$t_{(stg)}$		123		ns	
Fall time	$t_{(f)}$		9		ns	

### NOTES:

(\*) Measured under pulsed conditions. Pulse width =  $300\mu\text{s}$ . Duty cycle  $\leq 2\%$ .

## Typical characteristics

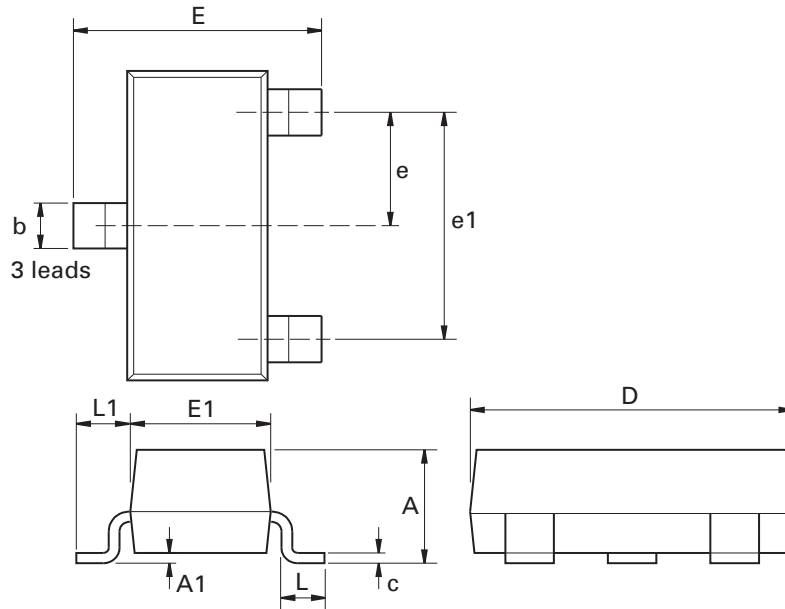


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## Package outline - SOT23



Dim.	Millimeters		Inches		Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	-	1.12	-	0.044	e1	1.90 NOM		0.075 NOM	
A1	0.01	0.10	0.0004	0.004	E	2.10	2.64	0.083	0.104
b	0.30	0.50	0.012	0.020	E1	1.20	1.40	0.047	0.055
c	0.085	0.20	0.003	0.008	L	0.25	0.60	0.0098	0.0236
D	2.80	3.04	0.110	0.120	L1	0.45	0.62	0.018	0.024
e	0.95 NOM		0.037 NOM		-	-	-	-	-

**Note:** Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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